

Gas-phase Synthesis of Silaformaldehyde (H₂SiO) and Hydroxysilylene (HSiOH) in Outflows of Oxygen-rich Asymptotic Giant Branch Stars

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Abstract

Silicon- and oxygen-containing species such as silicon monoxide (SiO) and silicon dioxide (SiO₂) represent basic molecular building blocks connected to the growth of silicate grains in outflows of oxygen-rich asymptotic giant branch (AGB) stars like R Doradus. Yet the fundamental mechanisms of the formation of silicate grains and the early processes that initiate the coupling of the silicon with the oxygen chemistries in circumstellar envelopes have remained obscure. Here, in a crossed molecular beams experiment combined with ab initio electronic structure calculations, we reveal that at least the *d*2-silaformaldehyde (D₂SiO) and *d*2-hydroxysilylene (DSiOD) molecules — proxies for the astronomically elusive silaformaldehyde (H₂SiO) and hydroxysilylene (HSiOH) molecules—can be synthesized via the reaction of the D1-silylidyne radical (SiD; $X^2\Pi$) with D2-water (D₂O) under single-collision conditions. This system represents a benchmark of a previously overlooked class of reactions, in which the silicon–oxygen bond coupling can be initiated by a reaction between the simplest silicon-bearing radical (silylidyne) and one of the most abundant species in the circumstellar envelopes of evolved oxygen-rich AGB stars (water). As supported by novel astrochemical modeling, considering that silicon- and oxygen-containing species like H₂SiO and HSiOH might be photolyzed easily, they ultimately connect to simple molecular precursors such as SiO that drive a chain of reactions conceivably forming higher molecular weight silicon oxides and, ultimately, a population of silicates at high temperatures.

Unified Astronomy Thesaurus concepts: Astrochemistry (75); Interstellar dust (836); Laboratory astrophysics (2004); Circumstellar envelopes (237)

1. Introduction

In recent decades, silicon- and oxygen-containing molecules like silicon monoxide (SiO; Reber et al. 2006, 2008; Gail et al. 2013; Liu & Jiang 2017; Takigawa et al. 2017; Cigan et al. 2019; Escatllar & Bromley 2020) and silicon dioxide (SiO₂; Fabian et al. 2000; Li & Draine 2002; Schneider et al. 2004; Nozawa et al. 2005; Loeffler et al. 2016) have been recognized as fundamental molecular building blocks eventually leading to the formation of silicate grains-nanoparticles consisting primarily of olivine-type ((Mg,Fe)₂SiO₄) refractory minerals stars like R Doradus and potentially in cold molecular clouds such as the Taurus molecular cloud 1 (TMC-1; Avramov et al. 2005; Ziurys 2006; Henning 2010; Jones & Nuth 2011; Goumans & Bromley 2012; Tielens 2012; Krasnokutski et al. 2014). However, the elementary reactions initiating and driving the complex networks of chemical reactions and molecular mass growth processes are still very contentious. This is because interstellar silicates are destroyed faster by sputtering from galactic cosmic rays once ejected into the interstellar medium (ISM) than synthesized during the late stages of stellar evolution through nucleation and reactions of silicon-/oxygenbearing molecules together with magnesium-type and ironbased oxides in circumstellar envelopes (CSEs) of oxygen-rich AGB and red supergiant stars (Gail & Sedlmayr 1999; Reber et al. 2006; Ziurys 2006; Reber et al. 2008; Henning 2010; Jones & Nuth 2011; Goumans & Bromley 2012; Tielens 2012; Gail et al. 2013; Gobrecht et al. 2016). This inconsistency is

reflected in the lifetimes of interstellar grains of a few 10⁸ yr compared to their formation rates of 3×10^9 yr (Tielens 1998; Draine 2009; Jones & Nuth 2011; Dwek 2016). Therefore, critical elementary reactions that involved in the mass growth processes of silicate grains are lacking. Interstellar silicates play a crucial role in star formation and hence in the origin of solar systems by impacting the radiation balance and in their role as "molecular factories" through the synthesis of complex organic molecules within their ice-coated surfaces (Abplanalp et al. 2016). Since even amino acids and (precursors to) sugars can be formed throughout their ice-coated surfaces through interaction with ionizing radiation in the form of energetic galactic cosmic rays and the internal vacuum ultraviolet radiation field present even deep inside molecular clouds, these nanoparticles have also been linked to the prebiotic evolution of the ISM (Wakelam et al. 2010). Consequently, the unraveling of the origin of silicates is of critical significance to the astrochemistry, astrobiology, and astrophysics communities to ultimately untangle the most fundamental processes that drive the formation of solar systems, including our own.

Here we reveal that the silaformaldehyde molecule (H₂SiO) and hydroxysilylene (HSiOH)—the isovalent species of the ubiquitous interstellar formaldehyde molecule (H₂CO; Fu et al. 2012), along with hydroxymethylene (HCOH; Mazarei & Mousavipour 2017; Simmie & Würmel 2020; Figure 1)—can be proficiently prepared through a high-temperature gas-phase chemistry. In a combined crossed molecular beam and electronic structure study, we report the formation of hitherto astronomically elusive d2-silaformaldehyde (D₂SiO) and d2-

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Figure 1. Molecular structures, point groups, relative energies (kJ mol⁻¹), bond distances (Å), and selected bond angles of formaldehyde (H₂CO), silaformaldehyde (H₂SiO), and their isomers. Carbon, silicon, oxygen, and hydrogen atoms are color coded in black, purple, red, and gray, respectively.

hydroxysilylene (DSiOD)—as a proxy for H₂SiO and HSiOH —via the bimolecular reaction of the D1-silylidyne radical (SiD; $X^{2}\Pi$) with D2-water (D₂O). This system exemplifies the surrogate for the reaction of the silylidyne radical (SiH) generated via photodissociation of silane (SiH₄; Glenewinkel-Meyer et al. 1993) with water (H₂O) to prepare gas-phase silaformaldehyde (H₂SiO) and hydroxysilylene (HSiOH) via a single collision event. This bimolecular reaction may represent a critical pathway to H₂SiO and HSiOH in high-temperature environments, such as the outflows of oxygen-rich AGB stars. Along with SiO and SiO₂, H₂SiO and HSiOH could drive a chain of reactions conceivably forming higher molecular weight silicon oxides and, ultimately, a population of silicates at high temperatures.

2. Results

2.1. Crossed Molecular Beam Studies: Laboratory and Centerof-mass Frame

The gas-phase reaction of the D1-silylidyne radical (SiD; $X^2\Pi$) with D2-water (D₂O; $X^{1}A_{1}$) was studied under single-collision conditions in a crossed molecular beam machine (Yang et al. 2021). Considering the natural isotope abundances of silicon (28 Si: 92.23%; ²⁹Si: 4.67%; ³⁰Si: 3.10%), the reactive scattering signal was collected at a mass-to-charge (m/z) of m/z = 48 and 46, which are related to the potential products upon the emission of atomic (²⁸SiD₂O⁺: m/z = 48; reaction (1)) and molecular deuterium $({}^{28}\text{SiDO}^+: m/z = 46; {}^{30}\text{SiDO}^+: m/z = 48; \text{ reaction (2)}) \text{ and}$ fragments generated via dissociative electron impact ionization of the parent molecule leading to 28 SiDO⁺ (m/z = 46). Time-of-flight (TOF) spectra were accumulated for up to 96 hr at each angle with ion counts at m/z = 46 emerging at a level of $50\% \pm 3\%$ compared to m/z = 48. These TOF spectra are superimposable after scaling (Figure A1); along with the isotopic substitution pattern, this finding suggests the existence of a single reaction channel, i.e., the reaction of the D1-silvlidyne radical (SiD; $X^2\Pi$) with D₂O forming SiD₂O isomer(s)—predominantly via the reaction of ²⁸SiD—along with the emission of atomic deuterium (D; 2 amu), yielding the

signal at m/z = 48 (²⁸SiD₂O, hereafter SiD₂O). The signal at m/z = 46 originates from dissociative electron impact ionization of the parent molecules. Consequently, the laboratory data suggest that the reaction of the D1-silvlidyne radical (SiD; $X^2\Pi$) with D₂O involves the formation of SiD₂O isomer(s) via the atomic deuterium emission. The resulting TOF spectra and the full laboratory angular distributions were collected at the best signal-tonoise ratio at m/z = 48 (SiD₂O⁺; Figure 2). This distribution is almost forward-backward symmetric around the center-of-mass (CM) angle of 43°,3 (Table A1) and spans a scattering angular range from 28°3 to 58°3. These results indicate that the reaction proceeds via indirect scattering dynamics involving the existence of SiD₃O intermediate(s) that ultimately dissociate to SiD₂O via atomic deuterium emission (Levine 2005). Note that, accounting for distinct recoil circles for the atomic and molecular deuterium loss channels (Figure A2), the ratio of the ion counts at m/z = 48(reaction (1)) versus 46 (reaction (2)) is determined to be 1 $(m/z = 48):0.04 \pm 0.01$ (m/z = 46). This may explain that the products of reaction (2) cannot be detected under our experimental conditions compared with the already weak scattering signal for reaction (1):

$$^{28}\text{SiD}(30 \text{ amu}) + D_2O(20 \text{ amu})$$

$$\rightarrow ^{28}\text{SiD}_3O(50 \text{ amu}) \rightarrow ^{28}\text{SiD}_2O \qquad (1)$$

$$(48 \text{ amu}) + D(2 \text{ amu}),$$

$$^{28}\text{SiD}(30 \text{ amu}) + D_2O(20 \text{ amu})$$

$$\rightarrow ^{28}\text{SiD}_3O(50 \text{ amu}) \rightarrow ^{28}\text{SiD}O(46 \text{ amu})$$

$$+ D_2(4amu).$$
 (2)

Our primary objective is to explore the nature of the SiD₂O isomer(s) along with the underlying reaction mechanism(s) on the pertinent SiD₃O potential energy surface(s) (PESs) accessed through the bimolecular reaction of the D1-silylidyne radical (SiD; $X^{2}\Pi$) with D₂O. To reach these goals, a forward convolution of the laboratory data into the CM reference frame generates the CM translational energy $P(E_{T})$ and angular $T(\theta)$ flux distributions



Figure 2. Laboratory angular distribution (top) and TOF spectra (bottom) collected at m/z = 48 for the reaction of the D1-silylidyne radical (SiD; X²II) with D2-water (D₂O). The black circles represent the experimental data, while the red lines define the best fits.

(Figure 3; Yang et al. 2021) via a transformation of the laboratory data to the CM frame. Within our error limits, the resulting best-fit CM functions (Figure 3) were achieved using a single channel of the product mass combination of 48 amu (SiD₂O) plus 2 amu (D). The resulting CM translational energy distribution $P(E_T)$ reveals a maximum translational energy release (E_{max}) of $37 \pm 10 \text{ kJ mol}^{-1}$. Considering the energy conservation, the maximum translational energy (E_{max}), collision energy (E_C), and reaction energy ($\Delta_r G$) are connected via $E_{\text{max}} = E_C - \Delta_r G$ with regard to the molecules born without rovibrational excitation. Therefore, the reaction energy is calculated to be $-10 \pm 10 \text{ kJ mol}^{-1}$. Furthermore, the $P(E_T)$ distribution peaked away from zero translational energy at 19 ± 5 kJ mol⁻¹, suggesting a tight exit transition state leading to SiD₂O molecules from the SiD₃O intermediates (Levine 2005). Further, the average translational energy of the products was derived to be $18 \pm 5 \text{ kJ mol}^{-1}$, suggesting that $49\% \pm 13\%$ of the available energy is transformed into the translational degrees of freedom of the products. Finally, the resulting CM angular distribution $T(\theta)$ depicts nonzero intensity over the complete scattering range from 0° to 180° , proposing indirect scattering dynamics via the formation of SiD₃O complex(es); the forwardbackward symmetry of $T(\theta)$ implies that the lifetime of the decomposing SiD₃O complex is longer than the rotational period (s) (Miller et al. 1967).

2.2. Electronic Structure Calculations and Reaction Mechanism

The electronic structure calculations identified the existence of two distinct SiDO isomers (p1-p2) that may be produced via molecular deuterium loss; further, four SiD₂O isomers (p3-p6)

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were identified that can be accessed through atomic deuterium emission (Figure 4). Our computations suggest that the reaction is initiated by the barrierless formation of a complex i1, which is stabilized by $50 \text{ kJ} \text{ mol}^{-1}$ with respect to the separated reactants and bound through a dative bond formed by donation of the lone oxygen atom to the empty p orbital of Si. This complex isomerizes via deuterium migration from the oxygen atom of the water to the SiD moiety, leading to the hydroxy-d3-silyl radical (D₂SiOD, i2, $X^{1}A'$ with an inherent barrier of 32 ± 5 kJ mol⁻¹. The hydroxyd3-silvl radical represents the global minimum of the SiD₃O PES. Our calculations also identified that a molecular deuterium loss from **i1** yields the product hydroxy-d-silvlidyne (SiOD, **p1**, $X^{1}A'$, $\Delta_r G = -131 \pm 5 \text{ kJ mol}^{-1}$ with an inherent barrier of $27 \pm$ 5 kJ mol^{-1} . Intermediate **i1** can emit atomic deuterium from the silicon atom, forming a van der Waals complex silicon-D2-water (SiOD₂, **p6**, ${}^{3}A''$, $\Delta_{r}G = 256 \pm 5 \text{ kJ mol}^{-1}$) in an overall endoergic reaction. The products trans-d2-hydroxysilylene (t-DSiOD, p4, X¹A', $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$) and cis-d2-hydroxysilylene (c-DSiOD, **p5**, $X^{1}A'$, $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$) can also be produced via atomic deuterium loss from il with transition states located 79 and 86 kJ mol^{-1} above the separated products, respectively. Note that the pathways $i1 \rightarrow p4/p5$ are not competitive due to the transition states ranging well above our collision energy of 27.3 ± 0.5 kJ mol⁻¹, which cannot be overcome under our experimental conditions. Intermediate i2 can isomerize via a deuterium shift from the oxygen atom to the silicon atom, yielding the d3-silyloxy intermediate (D₃SiO, i3, ¹A') via a barrier of 188 kJ mol^{-1} above intermediate i2. The product hydroxy-dsilylidyne (SiOD, p1, X¹A') can be accessed via molecular deuterium loss from i2 via a tight exit transition barrier lying 100 kJ mol^{-1} above the separated products, while the products *d*2-silaformaldehyde (D₂SiO, **p**3, X¹A', $\Delta_r G = -8 \pm 5$ kJ mol⁻¹), trans-d2-hydroxysilylene (t-DSiOD, **p4**, $X^{1}A'$, $\Delta_{r}G = -5 \pm$ 5 kJ mol⁻¹), and cis-d2-hydroxysilylene (c-DSiOD, **p5**, X¹A', $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$) can be formed via atomic deuterium loss from i2. Here the formation of d2-silaformaldehyde (D₂SiO, p3) occurs via an exit barrier of 18 kJ mol⁻¹, whereas p4 and p5 are produced via loose transition states without distinct exit barriers. The decomposition of **i3** yields the product oxo-silyl-d (DSiO, **p2**, ¹A', $\Delta_r G = -95 \pm 5 \text{ kJ mol}^{-1}$) via a molecular deuterium loss from **i3** via a tight exit transition state lying 96 kJ mol⁻¹ above the separated products. The product d2-silaformaldehyde (D₂SiO; **p3**) can be formed via atomic deuterium emission from i3 via a loose transition state.

We are now merging our experimental findings with the results from the ab initio calculations to propose the underlying reaction mechanism(s) along with the chemical dynamics of the reaction. The experimentally derived reaction energy of -10 ± 10 kJ mol⁻¹ is in good agreement with our computed value for an exoergic reaction of -8 ± 5 and -5 ± 5 kJ mol⁻¹ to synthesize the d2silaformaldehyde (D₂SiO, **p3**, $\Delta_r G = -8 \pm 5 \text{ kJ mol}^{-1}$), trans-d2hydroxysilylene (t-DSiOD, p4, $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$), and/or cis-d2-hydroxysilylene (c-DSiOD, **p5**, $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$) along with atomic deuterium. The silicon-D2-water complex (SiOD₂, **p6**, $\Delta_r G = 256 \pm 5 \text{ kJ mol}^{-1}$) is energetically not available considering the collision energy (E_C) of 27.3 kJ mol⁻¹. Consequently, we deduce that the d2-silaformaldehyde (D₂SiO; p3), trans-d2-hydroxysilylene (t-DSiOD; p4), and/or cis-d2hydroxysilylene (c-DSiOD; p5) are formed in the crossed molecular beam reaction of the D1-silvlidyne radical (SiD; $X^2\Pi$) with D_2O . The reaction of the D1-silylidyne radical (SiD; $X^2\Pi$) with D₂O proceeds via indirect scattering dynamics (complex



Figure 3. The CM translational energy flux distribution (a), the CM angular flux distribution (b), and the top view of the corresponding flux contour map (c) leading to the formation of *d2*-silaformaldehyde (D₂SiO) and *d2*-hydroxysilylene (cis-DSiOD and trans-DSiOD) plus atomic deuterium in the D1-silylidyne radical (SiD; $X^2\Pi$) with D2-water (D₂O) system. Shaded areas indicate the acceptable upper and lower error limits, while the red solid lines define the best fits. The flux contour map represents the flux intensity of the reactively scattered heavy products as a function of the CM scattering angle (θ) and product velocity (*u*). The color bar manifests the flux gradient from high (H) to low (L) intensity. The colors of the atoms are as follows: silicon (purple), oxygen (red), and deuterium (gray).

forming reaction) and is initiated with the formation of a bound dative complex i1. The collision complex i1 undergoes atomic deuterium migration to i2, with the latter ejecting a deuterium atom to form the products d2-silaformaldehyde (D₂SiO, p3, X¹A', $\Delta_r G = -8 \pm 5 \text{ kJ mol}^{-1}$), trans-*d*2-hydroxysilylene (t-DSiOD, **p4**, X¹A', $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$), and/or cis-*d*2-hydroxysilylene (c-DSiOD, **p5**, X¹A', $\Delta_r G = -5 \pm 5 \text{ kJ mol}^{-1}$). The product d^2 silaformaldehyde (D₂SiO, **p3**, X¹A', $\Delta_r G = -8 \pm 5 \text{ kJ mol}^{-1}$) can also be formed via the atomic deuterium emission from intermediate i3, which stems from the deuterium shift from the OD group to SiD_2 moiety in i2. It is instructive to compare the present results of the electronic structure calculations on the SiH₃O PES with those reported by Zachariah & Tsang (1995), who explored the thermochemistry, energetics, and kinetics of hightemperature Si_xH_yO_z reactions at the BAC-MP4 level of theory including, in particular, unimolecular decomposition of H₂SiOH and H_3SiO and its reverse reactions, although the SiH + H_2O channel was not considered in either direction. The agreement appears to be rather close, as the average unsigned difference in the relative energies of various species and barrier heights is only 6 kJ mol^{-1} , and the maximal deviation is 14 kJ mol^{-1}

To assess to what extent **p3–p5** could be formed in this experiment, we calculated the statistical yields of products **p1– p6** using Rice–Ramsperger–Kassel–Marcus (RRKM) theory (Table A3). These studies reveal that *d2*-silaformaldehyde (D₂SiO, **p3**), trans-*d2*-hydroxysilylene (t-DSiOD, **p4**), and cis*d2*-hydroxysilylene (c-DSiOD, **p5**) contribute 25%, 26%, and 49%, respectively, at $E_C = 27.3$ kJ mol⁻¹. For the product *d2*-silaformaldehyde (D₂SiO, **p3**), dissociation from **i2** and **i3** supplies 2% and 23%, respectively. Since the isomerization of **i1** to **i2** is a key link to form the products *d2*-silaformaldehyde (D₂SiO, **p3**), trans-*d2*-hydroxysilylene (t-DSiOD, **p4**), and cis*d2*-hydroxysilylene (c-DSiOD, **p5**) along with the atomic deuterium, it is critical to recall that a fit of the experimental data had to be obtained via the combination of a reaction threshold of $27-32 \text{ kJ mol}^{-1}$ with the fitting routine. In the fitting program, the collision energy ($E_{\rm C}$) and velocity distribution of each supersonic beam $f(v_i)$, with *i* being the primary SiD and secondary D₂O beam, are defined by

$$E_C = \frac{1}{2}\mu\nu_r^2,\tag{3}$$

$$\mu = \frac{m_{\rm SiD} * m_{\rm D_2O}}{m_{\rm SiD} + m_{\rm D_2O}},\tag{4}$$

$$\nu_r^2 = \nu_{\rm SiD}^2 + \nu_{\rm D_2O}^2,\tag{5}$$

$$f(v_{\rm SiD}) \propto v_{\rm SiD}^2 \exp\left(-\left(\frac{v_{\rm SiD}}{\alpha_{\rm SiD}} - S_{\rm SiD}\right)^2\right),$$
 (6)

$$f(v_{\rm D_2O}) \propto v_{\rm D_2O}^2 \exp\left(-\left(\frac{v_{\rm D_2O}}{\alpha_{\rm D_2O}} - S_{\rm D_2O}\right)^2\right),$$
 (7)

with the relative velocity ν_r , velocity v_i , reduced mass μ , mass of the reactant *m*, velocity v_i , speed ratio S_i , $\alpha_i = (2kT/m_i)^{1/2}$, temperature of the beam *T*, and Boltzmann's constant *k*. The fitting program convolutes over the apparatus functions including the velocity distributions and the velocity spreads. The corresponding relative velocity peaked at 2133 m s⁻¹, yielding a peak collision energy of $E_C = 27.3 \pm 3.4$ kJ mol⁻¹. Considering the computed barrier of the reaction connecting **i1** and **i2** of 32 ± 5 kJ mol⁻¹, around 50% of the collisions are sufficiently high to overcome this isomerization barrier. The resulting reaction cross section (σ) increases as the collision



Figure 4. Potential energy diagram of the reaction of the D1-silylidyne radical (SiD; $X^2\Pi$) with D2-water (D₂O) leading to **p1–p6**, calculated at the CCSD(T)-F12/cc-pVTZ-f12//B3LYP/6-311G(d,p) + ZPE(B3LYP/6-311G(d,p) level of theory. The numbers in blue refer to the reaction of the silylidyne radical (SiH; $X^2\Pi$) with water (H₂O). The energies are shown in kJ mol⁻¹ with respect to the energy of the separated reactants. Atoms are colored as follows: silicon (purple), oxygen (red), and deuterium (gray). Cartesian coordinates and normal modes are compiled in Table A7.

barrier to the reaction as derived from the line-of-center model (Kaiser et al. 1996; Alagia et al. 2000):

$$\sigma \propto 1 - \frac{E_0}{E_C}.$$
(8)

Laboratory investigations of these products are rare. Bogey et al. determined the structure of H₂SiO by rotational submillimeter-wave spectra (Bogey et al. 1996). The experimental results suggest that the bond lengths and angles were Si = O 1.515 Å, Si-H 1.472 Å, and \langle H–Si–H 112°.0. The Si = O stretching frequency was identified as 1202 cm⁻¹ via infrared spectroscopy of H₂SiO in an argon (Ar) matrix (Withnall & Andrews 1985). A frequency of 697 cm^{-1} is also obtained, which is assigned to the SiH₂ wag or SiH₂ rock. Our calculations reveal that, for the H₂SiO molecule, the bond lengths of Si = O and Si-H are 1.528 and 1.483 Å (Figure 1), respectively, along with the <H-Si-H of 111°.4, and the Si = O stretching frequency in H₂SiO is 1217 cm^{-1} (Table A7). These experimental identified structure parameters of the H₂SiO molecule are well reproduced in our calculation. Margrave and coworkers performed the reaction of silicon atoms with water in a solid argon matrix at a low temperature of 15 K (Ismail et al. 1982). The final products are confirmed as trans- and cis-HSiOH via the infrared spectrum. The trans-HSiOH carries Si-O, Si-H, and O-H bond lengths of 1.591 ± 0.100 , 1.521 ± 0.030 , and 0.958 ± 0.005 Å and <H-Si-O and <Si-O-H of 96°.6 \pm 4°.0 and 114°.5 \pm 6°, respectively. The frequencies of the H–O bond stretch, H–Si bond stretch, HSiO bending, Si–O bond stretch, SiOH bending mode, and out-of-plane torsion mode of trans-HSiOH are 3650.0, 1872.3, 937.0, 850.6, 722.6, and 659.1 cm⁻¹, respectively. Furthermore, the observed frequencies (cm⁻¹) of HSiOD, DSiOD, HSi¹⁸OH, HSi¹⁸OD, and DSi¹⁸OD are also included in this study. Our best computed geometry for HSiOH (Figure 1, Table A7) agrees within these experimental errors.

3. Astrophysical Implications

Our combined crossed molecular beam and high-level electronic structure calculational study provided compelling evidence on the facile formation of d2-silaformaldehyde (D₂SiO) and cis/trans-d2-hydroxysilylene (c/t-DSiOD) under single-collision conditions via the bimolecular gas-phase reaction of the D1-silylidyne radical (SiD; $X^2\Pi$) with D₂O. Since the critical isomerization barrier of $32 \pm 5 \text{ kJ mol}^{-1}$ is involved in this reaction, the mechanism may be open in high-temperature oxygen-rich AGB stars. To evaluate the influence of this reaction on the circumstellar chemistry, astrochemical modeling of the chemistry of oxygen-rich AGB stars was conducted. Rate coefficients for the reaction of silylidyne radicals (SiH) with water (H₂O) were computed over a range of

300-3000 K (Appendix A.2) and fitted with the sum of two de Kooij-Arrhenius expressions (Table A2). Considering the aforementioned energy barriers in the SiH-H₂O system, product formation is only open in the hot, inner CSE, where loss reactions with atomic oxygen $(O({}^{3}P))$ and hydroxyl radicals (OH), as well as photodissociation, are important. The rates of these neutral-neutral reactions were taken from Tokuhashi et al. (1990), the photodissociation rates for H₂SiO were extracted from the OSU09 database (Harada et al. 2010), and the photorates for oxo-silyl (HSiO) and silicon hydroxide (SiOH) were adopted from those of formyl (HCO) and hydroxy-methylidyne (COH) but increased by a factor of 5 to reflect the fact that silicon forms weaker bonds than carbon (Table A4). We note that in cases such as this, where the photodissociation cross sections are unknown, the photodissociation rates are highly uncertain, likely to within an order of magnitude. We report below the results of adopting the same photodissociation rate as for the formyl radical.

The models for the outflow exploited mass-loss rates (MLRs) of 10^{-6} and $8 \times 10^{-6} M_{\odot} \text{ yr}^{-1}$ with an outflow velocity of 15 km s⁻¹. We adopted a radial temperature distribution from Crossa & Menten (1997): $T(r) = 128 \times (10^{15}/r)^{4.7} + 447 \times (10^{15}/r)^{1.05} \text{ K}$, with the radius r given in centimeters. Since few dust grains survive at very high temperatures, a maximum temperature of 1500 K in the outflow was incorporated into the model. The effects of two different density profiles for the gas in the expanding CSE were investigated. One is the usual r^{-2} density distribution appropriate for a spherically expanding wind at constant velocity. The second explores that the flow is clumpy. In particular, we adopt a clump volume filling factor of 0.1 together with a void interclump medium, i.e., a one-component model as fully described in Van de Sande et al. (2018). Our initial fractional abundances of parent molecules at $r = 10^{14}$ cm are given in Table A5. These are taken from Agúndez et al. (2020), with the initial SiH_4 abundance from McElroy et al. (2013). We note that silane has only been detected in the CSE of the carbon-rich AGB star IRC+10216. The results for the radial distributions of the fractional abundances of HSiO, SiOH, and H₂SiO are presented in Figure 5 for MLRs of 10^{-6} and $8 \times 10^{-6} M_{\odot}$ yr⁻¹, respectively, and radial column densities for each of our four models-smooth and one-component outflowsare given in Table A6.

We note here that Gobrecht et al. (2016) studied dust formation driven by periodic shock waves in the inner envelope of the O-rich AGB star IK Tau, which has properties somewhat similar to those in our higher-MLR model. Their calculations cover chemistry between one and 10 stellar radii and indicate that HSiO and H₂SiO can be formed efficiently through successive H-abstraction reactions of SiO with H2. At four stellar radii, equivalent to our starting radius of 10^{14} cm, their calculated values are roughly 3×10^{-7} and 10^{-6} for HSiO and H₂SiO, respectively. We have run models with these species as parents. In this case, their total column densities can be approximated to within 10% by the product of their initial number density, $n(r_{\rm in})$, and the initial radius, $r_{\rm in}$. For an MLR = $10^{-6} M_{\odot} \,{\rm yr}^{-1}$, for example, the column densities are 2.2×10^{15} and $7.4 \times 10^{15} \,{\rm cm}^{-2}$ for HSiO and H₂SiO, respectively, much larger than those given by our model. The values of these initiating rate coefficients are not listed in the Gobrecht et al. paper or in the references they cite, but the endothermicity of SiO and H₂ equivalent to a temperature of 40,000 K and would be completely inefficient if introduced to our chemical model.

The radial fractional abundance and the column density of SiOH are about 100 times larger than those of HSiO, reflecting the



Figure 5. Fractional abundances with respect to molecular hydrogen as a function of radius for MLRs of (a) 10^{-6} and (b) $8 \times 10^{-6} M_{\odot} \text{ yr}^{-1}$. Solid lines: smooth model. Dotted lines: one-component model.

fact that the product channel of the SiH-H₂O system forming HSiO has a smaller preexponential value and larger energy barrier than that of SiOH. Over the range 300-1500 K, the rate coefficient of the channel to SiOH is 5-10 times larger than that to H₂SiO and 50-500 times larger than that to HSiO. The abundances at radii less than about 10¹⁶ cm are dominated by formation via the SiH-H2O reaction, while at larger radii, H2SiO is also formed from the reaction of OH with the silyl radical (SiH₃). The figures show that the one-component models lead to much higher fractional abundances compared to a smooth outflow, with an increase in the column densities of HSiO and SiOH around 100 and H₂SiO around 50 for lower MLRs, to 40 and 10, respectively, for higher MLRs. Although HSiOH has not yet been included in the model calculations due to unknown destruction routes, a rough estimate of its abundance under the assumption that its loss rates are similar to those of H₂SiO can be made so that their relative abundances reflect their relative formation rates, given by their respective formation rate coefficients in Table A2. Over the range 300-1500 K, the rate coefficients to trans-HSiOH and cis-HSiOH are about two and three times greater than that to H₂SiO. Hence, the column density of HSiOH (cis + trans) will be $(0.45-1.00) \times 10^{11}$ cm⁻² for the one-component models and at least an order of magnitude less for the smooth models. For MLRs greater than $10^{-5} M_{\odot} \text{ yr}^{-1}$, the extinction is so large that the radical species needed to drive the H–Si–O chemistry have low abundances, while for MLRs less than $10^{-6} M_{\odot} \text{ yr}^{-1}$, the extinction is so low that interstellar UV photons destroy species very effectively, and the abundances are also low. We have, in addition, investigated models in which the unshielded photodissociation rates of HSiO, SiOH, and H2SiO are

factors of 5 smaller. Although this affects the radial fractional abundances, the column densities change by less than a factor of 2. Overall, our detailed calculations show that the reaction between SiH and H₂O can produce HSiO, SiOH, H₂SiO, and cisand trans-HSiOH in the hot inner CSEs of O-rich AGB stars where the temperature is sufficiently large enough to overcome the substantial energy barriers to these product channels. Fractional abundances and column densities are generally larger in the one-component model due to the larger volume densities and shorter collision times within the clumps.

To sum up, the experiment proceeded at a collision energy of 27.3 kJ mol⁻¹, which represents a temperature of about 3284 K that corresponds to an upper limit for (effective) temperatures prevailing in the circumstellar environment of oxygen-rich stars close to the photosphere. This universal route represents a versatile reaction mechanism to "access" silicon-oxygen molecules through elementary neutral-neutral reactions involving the silvlidyne radical with oxides. Although not yet quantitatively verified, H₂SiO and HSiOH may photochemically degrade to the astronomically observed SiO (Rizzo et al. 2021). These pathways provide a population of silicon oxides that can possibly be set as a basis for the circumstellar silicates, thus leading us closer to solving the paradox of the injection and destruction timescales of silicates. The formation pathway of SiO in the CSEs of oxygenrich AGB stars through hydrogenated precursor molecules, which can then be photolyzed to eventually yield SiO, could represent a versatile conceptual pathway to silicon oxides. This route is parallel to the gas-phase preparation of silicon carbides such as silicon tricarbide (c-SiC₃) and silicon tetracarbide (SiC₄) potentially formed via photolysis of their hydrogenated precursors formed in the CSEs of carbon-rich AGB stars (Yang et al. 2019, 2021). Overall, as supported by models, the astronomical detection of H₂SiO and HSiOH in oxygen-rich CSEs and potential correlation with SiO would constrain the high-temperature chemistry and possibly the photochemistry in these oxygen-rich circumstellar environments, thus bringing us closer to the understanding of the most fundamental pathways to (precursors of) grains in circumstellar environments. Finally, we note that future observations of SiOH, HSiO, and/or H₂SiO in the inner regions of O-rich AGB stars would help differentiate between the routes to their formation proposed by us and Gobrecht et al. (2016).

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Conflict of interest

The authors declare no conflict of interest.

Appendix

A.1. Experimental Methods

The gas-phase reaction of the D1-silylidyne radical (SiD; $X^{2}\Pi$) with D2-water (D₂O; $X^{1}A_{1}$) was studied under single-collision conditions using a universal crossed molecular beam machine at the University of Hawai'i at Manoa (Kaiser et al. 2010; Yang et al. 2018). In the primary source chamber, a pulsed supersonic D1-silylidyne beam was produced in situ by laser ablation of a

Table A1

Peak Velocities (v_p) and Speed Ratios (S) of the D1-silylidyne Radical (SiD; X²II) with D₂-water (D₂O; X¹A₁) Beams along with the Corresponding Collision Energies (E_C) and CM Angles (Θ_{CM}) for the Reactive Scattering Experiment

Beam	$v_p \ ({\rm m \ s}^{-1})$	S	$E_{\rm C}$ (kJ mol ⁻¹)	$\Theta_{\rm CM}$ (deg)
$\frac{\text{SiD} (X^2 \Pi)}{\text{D}_2 \text{O} (X^1 A_1)}$	$\begin{array}{c} 1235\pm30\\ 1738\pm5\end{array}$	$\begin{array}{c} 8.2\pm2.0\\ 18.8\pm0.5\end{array}$	27.3 ± 0.5	43.3 ± 0.7

rotating silicon rod at 266 nm, 4 ± 1 mJ pulses (Spectra-Physics Quanta-Ray Pro 270 Nd:YAG laser; 30 Hz), and seeding the ablated species in a gas mixture of deuterium gas (D₂, 99.7%; Icon Isotopes, Inc.) and neon (Ne, 99.999%; Specialty Gases of America) with a ratio of 1:1 and a total pressure of 4 atm. Since the silicon atom has natural isotope abundances (²⁸Si, 92.23%; ²⁹Si, 4.67%; ³⁰Si, 3.10%), the intensity optimization of the D1silvlidyne beam was conducted at m/z = 31, and no higher molecular weight silicon-/deuterium-bearing species were detected. Although the supersonic beam carries some groundstate silicon atoms (Si(³P)), these silicon atoms (Si(³P)) were found not to react with D2-water under our experimental conditions. The D1-silylidyne beam passed through a skimmer and was velocity-selected by a four-slit chopper wheel, resulting in a well-defined peak velocity (v_p) and speed ratio (S) of 1235 \pm 30 m s^{-1} and 8.2 ± 2.0 (Table A1), respectively. In the secondary source chamber, the pulsed supersonic beam of D_2 -water (D_2O_2 , 99.9%; Sigma-Aldrich) seeded in helium (99.9999%; Airgas) at a fraction of 5% at 550 torr with a peak velocity of $v_p = 1738 \pm 5 \text{ m s}^{-1}$ and a speed ratio of $S = 18.8 \pm 0.5$ crossed perpendicularly with the primary D1-silylidyne beam in the main chamber. This resulted in a collision energy $(E_{\rm C})$ of $27.3 \pm 0.5 \text{ kJ mol}^{-1}$ and a CM angle (Θ_{CM}) of $43^{\circ}.2 \pm 0^{\circ}.7$ (Table A1). Each supersonic beam was released by a piezoelectric pulsed valve that was operated at 60 Hz, a pulse width of 80 μ s, and a peak voltage of -400 V. Note that even if D1-silylidyne radicals in the $A^2\Delta$ state are formed initially, taking into account the short lifetime of around 500 ns (Bauer et al. 1984), they will decay to the ground-state $X^2\Pi$ during a travel time of about 18 μ s to the interaction region in the main chamber.

The neutral reaction products (Figure A1 and Figure A2) entering the detector were ionized by an electron impact ionizer (80 eV; Yang et al. 2018), then filtered according to the massto-charge ratio (m/z) utilizing a quadrupole mass spectrometer (Extrel, QC 150) and eventually recorded by a Daly-type ion counter (Yang et al. 2018). The detector is housed within a triply differentially pumped and rotatable chamber that allows the collection of angularly resolved TOF spectra in the plane defined by both reactant beams. To obtain the information on the reaction dynamics, a forward-convolution method was used to transform the laboratory frame data into the CM frame (Yang et al. 2018), which represents an iterative method whereby user-defined CM translational energy $P(E_T)$ and angular $T(\theta)$ flux distributions are varied iteratively until a best fit of the laboratory frame TOF spectra and angular distributions is achieved. These functions comprise the reactive differential cross section $I(\theta, u)$, which is taken to be separable into its CM scattering angle θ and CM velocity *u* components, $I(u, \theta) \sim P(u) \times T(\theta)$. The error ranges of the $P(E_T)$ and $T(\theta)$ functions are determined within the 1σ limits of the corresponding laboratory angular distribution and beam parameters



Figure A1. The TOF spectra collected at m/z = 48 and 46 for the reaction of the D1-silylidyne radical (SiD; X² Π) with D2-water (D₂O; X¹A₁) at a CM angle of 44°.



Figure A2. Corresponding Newton diagrams for the reaction of the D1-silylidyne radical (SiD; $X^{2}\Pi$) with D2-water (D₂O; $X^{1}A_{1}$). The circles hold a radius equivalent to the maximum CM velocity of the thermodynamically most stable products, hydroxy-*d*-silylidyne (SiOD, **p1**, $X^{1}A'$, $\Delta_{r}G = -131 \pm 5$ kJ mol⁻¹), oxo-silyl-*d* (DSiO, **p2**, ¹A', $\Delta_{r}G = -95 \pm 5$ kJ mol⁻¹), *d*2-silaformaldehyde (D₂SiO, **p3**, $X^{1}A'$, $\Delta_{r}G = -8 \pm 5$ kJ mol⁻¹), cis-*d*2-hydroxysilylene (c-DSiOD, **p4**, $X^{1}A'$, $\Delta_{r}G = -5 \pm 5$ kJ mol⁻¹), respectively.

(beam spreads, velocities) while maintaining a good fit to the laboratory TOF spectra.

A.2. Theoretical Methods

Geometries of the reactants, products, intermediates, and transition states involved in the silylidyne reaction with water were optimized using the hybrid B3LYP (Becke 1993) density functional theory (DFT) method with the 6-311G(d,p) basis set (Table A7). Vibrational frequencies of all species were computed at the same B3LYP/6-311G(d,p) level of theory, taking into account the particular isotopic composition of the ${}^{28}Si^{16}OD_3/{}^{28}Si^{16}OH_3$ species involved in the SiD + D₂O/SiH

+ H₂O reactions, respectively. For the reactants and critical transition states involved in the pathways for molecular hydrogen loss from the dative complex i1 (i1 \rightarrow p1) and H atom migration in this complex $(i1 \rightarrow i2)$, geometry optimization was also carried out at the doubly hybrid DFT B2PLYPD3/6-311G(d,p) level of theory (Goerigk & Grimme 2011) incorporating a dispersion correction (Grimme et al. 2011) and at the coupled clusters CCSD/6-311G(d,p)level (Scuseria & Schaefer 1989). For the B2PLYPD3/6-311G (d,p) optimized structures, the vibrational frequencies were recalculated using the same method. Single-point energies were subsequently improved at the explicitly correlated coupled cluster CCSD(T)-F12 level (Knizia et al. 2009) with single and double excitations and perturbative treatment of triple excitations. The CCSD(T)-F12 calculations were carried out with the cc-pVQZ-f12 basis set (Dunning 1989) for most structures, whereas for the critical transition states $i1 \rightarrow p1$ and $i1 \rightarrow i2$, additional CCSD(T)-F12/cc-pVTZ-f12 calculations were also performed, and the energies were then extrapolated to the complete basis set (CBS) limit using the two-point formula, $E_{\text{CBS}} = E_{\text{cc-pVQZ-f12}} + (E_{\text{cc-pVQZ-f12}} - E_{\text{cc-pVTZ-f12}}) \times 0.69377$ (Martin & Uzan 1998). For the reactants and the two critical transition states, the CCSD(T)-F12/CBS energies were calculated not only for B3LYP but also for B2PLYPD3 and CCSD optimized geometries. For these species, the energies were further refined by taking into account the core electron correlation effects via CCSD(full,T)-F12 calculations with the cc-pCVTZ-f12 and cc-pCVQZ-f12 basis sets (Hill et al. 2010) extrapolated to the CBS limit, which included all core electrons except 1 s of Si atoms in the correlation treatment. Finally, anharmonicity corrections to zero-point vibrational energies were evaluated through calculations of anharmonic frequencies at the B3LYP/6-311G(d,p) level of theory using vibrational perturbation theory to the second order (VPT2) (Barone 2005). The B3LYP and B2PLYPD3 calculations, CCSD geometry optimizations, and VPT2 computations of anharmonic frequencies were performed using the GAUSSIAN 09 package (Frisch et al. 2009), whereas the CCSD(T)-F12 calculations were carried out employing MOLPRO 2010 (Werner et al. 2010). It should be noted that the relative CCSD(T)-F12/CBS energies of the $i1 \rightarrow p1$ and $i1 \rightarrow i2$ transition states including the core correlation and anharmonic ZPE corrections with their geometries optimized using B3LYP, B2PLYPD3, and CCSD agreed with the CCSD(T)-F12/cc-pVQZ-f12//B3LYP/6-311G(d,p) + harmonic ZPE(B3LYP/6-311G(d,p)) energies within 1 kJ mol⁻¹.

Product branching ratios in the $SiD + D_2O$ reaction under single-collision conditions and at the experimental collision energy of 27.3 kJ mol⁻¹ were evaluated using RRKM calculations (Steinfeld et al. 1982) of unimolecular rate constants for the reaction steps beginning with the i2 intermediate. Here the rate constants were evaluated as functions of the available internal energy of each intermediate or transition state within the harmonic approximation using B3LYP/6-311G(d,p) frequencies, with the internal energy assumed to be equal to the chemical activation energy, that is, negative of the relative energy of a species with respect to the reactants, plus the collision energy. Only one energy level was considered throughout at a zero-pressure limit reproducing the conditions in crossed molecular beams. For the H elimination reaction steps occurring via loose transition states without distinct exit barriers ($i2 \rightarrow p4/p5$ and $i3 \rightarrow p3$), variational RRKM theory

-687.16

 Table A3

 Statistical Branching Ratios (%) for the Reaction of the D1-silylidyne Radical (SiD; $X^2\Pi$) with D2-water (D₂O)^a

p1	p2	p3 (from i2)	p3 (from i3)	p4	р5
41.6	1.0	1.0 (2.0) ^b	12.9 (22.5) ^b	15.2 (26.4) ^b	28.2 (49.1) ^b

Notes.

Total

^a Computed at the experimental collision energy of 27.3 kJ mol⁻¹ considering **i2** as the decomposing intermediate.

3.4025

^b The numbers in parentheses show branching ratios among the D loss products only.

Rate Coefficients of the Silylidyne–Water Reaction as a Sum of Two Modified Arrhenius Expressions: $k = A_1 \times (T/300)^{n1} \times \exp(-E_l/T) + A_2 \times (T/300)^{n2} \times \exp(-E_2/T)$										
Channel	$A_1 \ ({\rm cm}^3 \ {\rm s}^{-1})$	n_1	<i>E</i> ₁ (K)	$A_2 \ ({\rm cm}^3 \ {\rm s}^{-1})$	<i>n</i> ₂	<i>E</i> ₂ (K)				
$SiOH + H_2$	3.64E-14	2.4619	1748.9	7.56E-16	2.7492	48.044				
$HSiO + H_2$	1.49E-15	2.1333	2949.0	3.27E-17	2.5685	987.76				
$H_2SiO + H$	1.70E-15	3.2836	2175.4	5.33E-17	3.5726	454.71				
t-HSiOH + H	5.04E-16	4.1114	1045.4	4.11E-20	4.8323	-1530.4				
c-HSiOH + H	1.49E-15	3.7393	1252.6	1.59E-19	4.4594	-1332.5				

1040.6

Table A2

(Steinfeld et al. 1982) was employed. Here the minimal energy reaction paths (MEPs) were scanned at the B3LYP/6-311G(d, p) level along the bond distances for the breaking Si-H bonds with all other geometric parameters being optimized. Vibrational frequencies for the optimized structures were then computed at the same level of theory, with the normal mode corresponding to the reaction coordinate projected out. Singlepoint energies of these MEP structures were recomputed at CCSD(T)-F12/cc-pVQZ-f12. These structures were then considered as transition-state candidates, and rate constants for the H losses from i2 and i3 were evaluated with these candidates. In each case, the minimal rate constant was selected as the true rate constant corresponding to a particular collision energy. The conventional and variational RRKM rate constants were used to evaluate product branching ratios by solving firstorder kinetic equations within steady-state approximation (Kislov et al. 2004). It should be noted that from the dative complex i1, the reaction flux can branch not only to i2 but also to **p1**, thus increasing the yield of this product. However, since the predicted energies of the $i1 \rightarrow p1$ and $i1 \rightarrow i2$ transition states are within our expected error bars of $\pm 5 \text{ kJ mol}^{-1}$ from the experimental collision energy and the D2 loss product could

9.84E-15

not be experimentally detected, we did not consider the $i1 \rightarrow p1$ pathway in the present calculations, keeping in mind that the computed yield of p1 (Table A3) is likely underestimated.

3.6986

5.27E-17

Additionally, RRKM master equation (ME) calculations (Fernández-Ramos et al. 2006) were carried out to evaluate temperature-dependent total and individual product channel rate constants for the SiH + H₂O reaction in the temperature range from 300 to 3000 K in the limit of zero pressure (Table A2 and Table A4). The MESS program package (Georgievskii et al. 2013; Georgievskii & Klippenstein 2015) was used for the calculations where the rigid rotor-harmonic oscillator approximation was employed in the evaluation of partition functions. All channels on the PES depicted in Figure 4 were included in the RRKM ME calculations, excluding only the highly unfavorable p6 + H route. Rate constants for the barrierless H elimination channels were assessed using variational RRKM theory as described above. For the astrochemical modeling, the initial fractional abundances of parent molecules and radial column densities for our models are reflected in Tables A5 and A6, respectively.

 Table A4

 New Reactions and Rate Coefficients Included in Our Chemical Model

Reaction	$A (cm^3 s^{-1})$	n	<i>E</i> (K)	Note
$\rm SiH + H_2O \rightarrow SiOH + H_2$				Table A2
$SiH + H_2O \rightarrow HSiO + H_2$				Table A2
$SiH + H_2O \rightarrow H_2SiO + H$				Table A2
$O+SiH_3{\rightarrow}H_2SiO+H$	2.16E-10	0.0	1005.0	Kushner (1993)
$OH + SiH_3 \rightarrow H_2SiO + H_2$	8.30E-12	0.0	0.0	Tokuhashi et al. (1990)
$SiOH + hv \rightarrow SiO + H$	5.00E-09	0.0	1.7	See text
$HSiO + hv \rightarrow SiO + H$	5.00E-09	0.0	1.7	See text
$H_2SiO + hv \rightarrow SiO + H_2$	4.40E-10	0.0	1.6	Harada et al. (2010)
$H_2SiO + h\upsilon \rightarrow HSiO + H$	2.20E-10	0.0	1.6	Harada et al. (2010)
$H_2SiO + hv \rightarrow SiOH + H$	2.20E-10	0.0	1.6	Harada et al. (2010)
$O + HSiO \rightarrow SiO + OH$	1.66E-10	0.0	0.0	Tokuhashi et al. (1990)
$O + SiOH \rightarrow SiO + OH$	1.66E-10	0.0	0.0	Tokuhashi et al. (1990)
$OH + HSiO \rightarrow SiO + H_2O$	1.66E-10	0.0	0.0	Tokuhashi et al. (1990)
$OH + SiOH \rightarrow SiO + H_2O$	1.66E-10	0.0	0.0	Tokuhashi et al. (1990)
$OH + H_2SiO \rightarrow HSiO + H_2O$	6.25E-12	0.0	85.4	Kushner (1993)
$OH + H_2 SiO \rightarrow SiOH + H_2 O$	6.25E-12	0.0	85.4	Kushner (1993)

Note. Rate coefficients are fitted to the modified Arrhenius formula: $k = A \times (T/300)^n \times \exp(-E/T)$.

Table A6							
Radial Column Densities (cm ⁻²) of HSiO, SiOH, and H ₂ SiO with MLRs in							
Units of $M_{\odot} \mathrm{yr}^{-1}$							

H ₂ O	2.2E-4	СО	3.0E-4	CO ₂	3.0E-7
SO	3.1E-6	SO ₂	3.7E-6	SiO	2.7E-5
N ₂	4.0E-5	NH ₃	6.3E-7	HCN	2.6E-7
H ₂ S	1.8E-5	CS	5.6E-8	SiS	9.5E-7
SiH ₄	2.2E-7	РО	7.8E-8	PN	1.5E-8

	10-	$^{-6} (M_{\odot} \mathrm{yr}^{-1})$	8×1	$0^{-6} (M_{\odot} \mathrm{yr}^{-1})$
	Smooth	One-component	Smooth	One-component
HSiO	2.18E7	1.56E9	3.48E7	4.85E8
SiOH	1.17E9	1.25E11	8.05E8	3.17E10
H ₂ SiO	4.44E8	2.04E10	9.41E8	9.14E9

Table A7

Optimized Cartesian Coordinates and Vibrational Frequencies for All Intermediates, Transition States, Reactants, and Products Involved in the Reactions of the D1silylidyne Radical (SiD) with D2-water (D₂O)

Snecies	Vibratio	onal Frequencies	(cm^{-1})		Cartesian	Coordinates (Å)	
opecies				Atom	Х	Y	Z
SiH	2014.8481			Si	0.000000	0.000000	0.102349
				Н	0.000000	0.000000	-1.432882
SiD	1449.7967						
H ₂ O	1639.2716	3811.1362	3907.5232	0	0.000000	0.000000	0.118805
				н ц	0.000000	0.756594	-0.475218
DaO	1199 4323	2748 1429	2862 1539	11	0.000000	-0.750594	-0.475218
i1 (SiH ₂ O)	163.8095	286.1448	415.8619	0	-1.257160	-0.002868	-0.094400
(488.6573	791.9714	1618.5760	Н	-1.617859	0.768975	0.357496
	1982.1953	3791.9061	3895.5162	Н	-1.680034	-0.782395	0.283405
				Si	0.896473	-0.099819	0.010210
				Н	0.804551	1.433823	-0.028643
i1 (SiD ₃ O)	117.4637	280.3143	310.9353				
	349.0965	586.3287	1186.9695				
	1427.0895	2731.7348	2858.0185				
i2 (SiH ₃ O)	273.0302	678.3959	773.7069	0	-1.081250	-0.108894	0.073658
	822.0908	878.2942	929.0702	Н	-1.626269	0.643843	-0.167344
	2127.4851	2203.9087	3889.3263	H	1.130577	-1.241582	0.450287
				S1	0.572474	0.019512	-0.107/24
:2 (S:D O)	100 4297	490.0011	507 5(1)	Н	1.131063	1.195/33	0.635931
$12(S1D_3O)$	(40.2224	489.9011	587.5613				
	640.3224	663.3957	848.7412				
3 (SH O)	1524.8702	1591.4035	2832.3135	0	1 102649	0.000407	0.026404
$13 (S1H_3O)$	534.9421 885 0180	554.7795	820.0408	0	-1.193048	0.000497	0.020494
	865.0169 2171 1150	909.4044	1000.5176	51 L	0.477002	1.226247	0.002383
	21/1.1159	2227.0489	2228.3103	п u	0.730000	0.025321	1 460464
				п u	1.060577	-0.025521	-1.409404
i3 (SiD ₂ O)	405 9428	125 2380	637 9514	11	1.009377	-1.200445	0.052582
$\mathbf{B}(\mathbf{SID}_{3}\mathbf{O})$	650 7685	712 2000	828 4441				
	1553 9518	1597 4603	1610 1898				
HaSiO	705 8736	711 6375	1023 2253	0	-1.088273	0.000000	0.000000
112010	1217.3128	2222.6821	2238 5022	Si	0.439901	0.000000	0.000000
	1217.5120	2222.0021	2230.3022	Н	1.273785	-1.226725	0.000000
				Н	1.273785	1.226725	0.000000
D ₂ SiO	545.2099	548.3482	736.2809				
2	1202.6165	1598.3974	1620.9361				
trans-HSiOH	695.4915	799.8918	842.8505	0	-0.027062	1.035054	0.000000
	948.8154	2007.9220	3850.7009	Si	-0.027062	-0.638894	0.000000
				Н	-0.904018	1.431685	0.000000
				Н	1.499388	-0.767596	0.000000
trans-DSiOD	508.0389	577.8436	709.9203				
	839.4854	1445.9984	2803.7344				
cis-HSiOH	657.1015	713.0332	848.8560	0	-1.030575	-0.094783	0.000000
	964.5395	1912.7466	3846.9066	Si	0.635981	-0.100844	0.000000
				Н	-1.517322	0.734954	0.000000
				Н	0.858184	1.435123	0.000000
cis-DSiOD	487.9168	508.8808	728.9761				
	848.0702	1376.8725	2801.7423				
HSiO	615.4602	1157.7019	1902.8167	0	0.058836	1.034771	0.000000
				Si	0.058836	-0.503833	0.000000
56.0		1150 0	1051 0000	Н	-1.294392	-1.224509	0.000000
DSIO	463.7706	1153.0591	1371.8020	0	0.02/20/	0.0005555	0.000000
SIOH	743.0187	861.6904	3816.9934	0	0.036206	0.992557	0.000000
				Si	0.036206	-0.672658	0.000000
SOD	554 0175	0 47 4710	0700 1705	Н	-0.796525	1.4/6/58	0.000000
SIUD Si IL O $(trial-t)$	554.3175	847.4712	2/80.1795	0	1 057650	0.000000	0 100103
$51H_2O$ (triplet)	263.5334	412./3/1	498.2755	0	-1.25/659	0.00000	-0.100103
	1617.2647	3/81.9/14	3882.9591	H	-1.025161	0.774143	0.343288
				H	-1.025150	-0.//4146	0.545286
Si D Q (triplat)	250 1/75	200 6601	261 0275	51	0.950828	0.000000	0.008161
SID_2O (unplet)	239.10/5	200.0091	301.83/3				

(Continued)								
Species	Vibratio	nal Frequencies	(cm^{-1})		Cartesian	Coordinates (Å)		
				Atom	Х	Y	Z	
	1184.9672	2724.9481	2848.0461					
Transition state i1 (SiH ₃ O) \rightarrow SiOH	-1400.9151	528.8608	575.5362	0	1.133076	-0.080506	-0.112710	
	746.4277	1032.4168	1269.4738	S1	-0.7/9828	-0.112682	0.005266	
	1810.1411	1850.7445	3821.04/1	н	1.380424	-0.403996	0.074055	
				п	-0.208617	1.070201	0.004384	
Transition state i1 (SiD ₂ O) \rightarrow SiOD	-1019.1304	388 1533	545 1091	11	-0.290017	1.555557	0.007512	
	566.3211	767.8341	908.9180					
	1288.1269	1325.0818	2782.5891					
Transition state $i1 \rightarrow i2$ (SiH ₃ O)	-1407.5419	498.4742	585.8171	0	-1.173301	-0.071804	-0.093167	
	636.5558	855.7707	988.9698	Н	-1.561332	0.797113	0.088421	
	1610.1571	2007.0335	3760.4889	Н	-0.525862	-0.454681	0.978144	
				Si	0.757613	-0.085081	-0.036841	
				Н	0.867025	1.423132	0.194544	
Transition state $i1 \rightarrow i2$ (SiD ₃ O)	-1030.6139	416.1471	450.8609					
	499.2646	638.6138	726.5557					
Transition state 11 (Cill O) trans UCOU	1159.4091	1444.7199	2737.7769	0	1 004451	0.002122	0 107(28	
Transition state II $(S1H_3O) \rightarrow trans-HS1OH$	-1589.2972	396.8614	530.8728	0	-1.004451	-0.002123	-0.10/638	
	003.8441	2036.0604	3768 3883	п	-1.960409	0.795349	0.555062	
	1090.4947	2030.9094	5708.5885	Si	0.750545	-0.002763	0.044049	
				н	0.921058	1 386016	-0.290899	
Transition state i1 (SiD ₂ O) \rightarrow trans-DSiOD	-1203.2188	291 6748	401.3395		0.921030	1.500010	0.270077	
Transition state II (01230) / Italis 20102	496.3244	622.1531	677.0021					
	807.6755	1466.3451	2745.1006					
Transition state i1 (SiH ₃ O) \rightarrow cis-HSiOH	-1596.5978	346.2718	549.8153	0	-1.011737	-0.002947	-0.114734	
	614.9327	709.7792	887.5530	Н	-1.373075	0.894739	-0.123617	
	1068.7653	1956.7803	3766.9971	Н	-1.986170	-0.588000	0.712605	
				Si	0.751343	-0.117642	-0.003778	
				Н	0.934335	1.363826	0.381785	
Transition state i1 $(SiD_3O) \rightarrow cis-DSiOD$	-1211.4184	251.6288	419.3693					
	452.6710	610.4910	703.7977					
	789.0757	1408.9818	2743.6099	0	1.12(1(0	0.000000	0 10 15 20	
Transition state $12 \rightarrow 13$ (SiH ₃ O)	-16/6.15/8	579.1946	662.6489	0	1.126169	0.000000	0.134529	
	1028 5512	899.3032	990.5754	51	-0.504482	0.000000	-0.036492	
	1920.3313	2203.0780	2220.2997	п	-1.278872	1 222301	0.207/11	
				н	-1.278876	-1.222391	0.297417	
Transition state $i2 \rightarrow i3$ (SiD ₂ O)	-1222.6468	415.0494	505.5388		1.270070	1.222505	0.297417	
	576.9668	706.4093	896.1591					
	1383.1707	1582.5430	1611.6356					
Transition state i2 (SiH ₃ O) \rightarrow SiOH	-1749.8514	498.6626	572.0371	0	1.070304	0.183968	0.005607	
· •	771.1815	793.9667	895.2493	Si	-0.570273	-0.222402	0.023932	
	1436.4522	1633.5555	3857.3788	Н	1.641943	-0.569268	-0.171850	
				Н	-1.248187	0.964666	-0.808212	
				Н	-0.972368	1.246487	0.600157	
Transition state i2 $(SiD_3O) \rightarrow SiOD$	-1275.1456	366.2297	418.7408					
	558.5353	662.1445	791.8439					
	1023.4244	1176.2372	2808.6873	0	1.040642	0.170.400	0.401/025	
Transition state	- /00.9140	180.4691	292.9968	0	-1.048643	0.170499	0.431625	
$12 (S1H_3O) \rightarrow H_2S1O$	690.8302	695.0297	1009.7754	Н	-2.122148	0.931260	-0.781565	
	1147.0380	2227.0951	2230.0740	H C:	1.103489	-1.100049	-0.220666	
				ы Ц	1 438324	-0.011737	0.410401	
Transition state	-5127540	132,2586	223 5982	11	1.+30324	1.0110/0	0.07+339	
i2 $(SiD_3O) \rightarrow D_2SiO$	524 6181	539,8339	727.9412					
- (30) - 22010	1124.5128	1598.4097	1630.0224					
Transition state i3 (SiH ₃ O) \rightarrow HSiO	-1162.6658	483.8049	628.4198	0	-1.147018	0.091275	0.053280	
	819.6700	957.6363	1136.3586	Si	0.374316	-0.121489	-0.081223	
	1258.8931	1933.4974	2275.2445	Н	1.224900	-1.213129	0.423347	
				Н	1.349476	1.070498	-0.383550	
				Н	1.361341	1.113285	0.671087	
Transition state i3 (SiD ₃ O) \rightarrow DSiO	-852.4192	377.4341	487.0344					

(Continued)								
Species	Vibrational Frequencies (cm ⁻¹)				Cartesian Coordinates (Å)			
				Atom	Х	Y	Z	
	585.8289	683.4504	904.2556					
Transition state trans-HSiOH + H \rightarrow HSiO + H_2	1121.4387	1391.6601	1642.1905					
	-1755.1382	381.9624	418.4205	0	0.847468	0.398251	0.000000	
	765.4431	860.9609	978.8453	Si	-0.684173	-0.211160	0.000000	
	1093.6062	1474.2482	1967.4913	Н	-1.284218	1.201129	0.000000	
				Н	1.701085	-0.334943	0.000000	
				Н	2.381807	-1.095952	0.000000	
Transition state trans-DSiOD + D \rightarrow DSiO + D ₂	-1271.5678	293.4724	305.3049					
	564.5316	701.3010	785.2250					
	845.0513	1085.0419	1415.6973					

Table A7

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